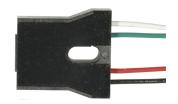
OPB739RWZ

Features:

- Focused for maximum sensitivity
- **Phototransistor Output**
- 650 nm Visible Red LED to optimize detection of dye based inks
- Low-cost plastic housing
- 24" minimum 26 AWG wire leads
- Optimal operating distance range 0.015" [.38 mm] to 0.045" [1.14 mm]

Electronics



Description:

The OPB739RWZ is a reflective line reader sensor. The sensor utilizes a visible red (650 nm) LED and an NPN silicon phototransistor mounted side by side on converging optical axes in a black plastic housing. The converging light beam makes this sensor capable of detecting line widths as small as 0.004" [0.1 mm] at the optimum distance of 0.030" [0.76 mm] from the target. The red LED maximizes the reflected signal contrast of black lines on white backgrounds. Recommended line spacing is .050" minimum.

This sensor can be used with Optek's OCB100CZ auto calibration module to reduce variability from sensor to sensor and to achieve a digital output.

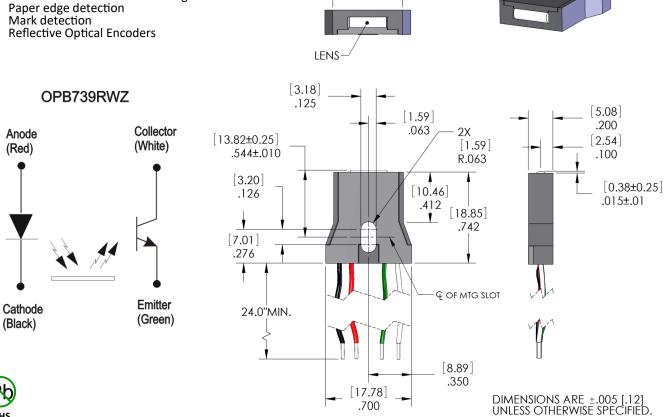
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.568

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Line Reading
- Low Resolution Bar Code Sensing





TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.



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OPB739RWZ



Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage and Operating Temperature Range	-40° C to +85° C			
Input LED				
Forward DC Current	40 mA			
Reverse DC Voltage	2 V			
Power Dissipation	100 mW			
Output Phototransistor				
Collector-Emitter Voltage	30 V			
Emitter-Collector Voltage	5 V			
Power Dissipation	100 mW			

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
Input IR LED							
V_{F}	Forward Voltage	1.2	2.0	2.3	V	I _F = 20 mA	
I _R	Reverse Current	-	-	100	μΑ	V _R = 2 V	
λ_{P}	Peak Emission Wavelength	-	650	-	nm	I _F = 20 mA	
Output Phototransistor							
$V_{(BR)CE0}$	Collector Emitter Breakdown Voltage	30	-	-	٧	Ι _C = 100 μΑ	
$V_{(BR)ECO}$	Emitter Collector Breakdown Voltage	5	-	-	٧	Ι _Ε = 100 μΑ	
I _{CEO}	Collector Dark Current	-	-	100	nA	V _{CE} = 10 V, I _F = 0	
t _r	Rise Time	-	300	-	μs	$V_{CE} = 5 \text{ Volts}^{(3)}$ $I_C = 1 \text{ mA}$ $R_L = 20 \text{ K}\Omega$	
t _f	Fall Time	-	300	-	μs		
Coupled Characteristics							
I _{C(ON)}	On-State Collector Current	0.25	-	-	mA	d = 0.030" (76 mm) ⁽¹⁾⁽²⁾ I _F = 20 mA, V _{CE} = 5 V	
V _{CE(SAT)}	Collector Emitter Saturation Voltage	-	-	0.4	V	d = 0.030" (76 mm) ⁽¹⁾⁽²⁾ I _C = 50 μA, I _F = 20 mA	
I _{CX}	Crosstalk Collector Current	-	-	0.05	mA	I _F = 20 mA, V _{CE} = 5 V No reflective test surface present	

Notes:

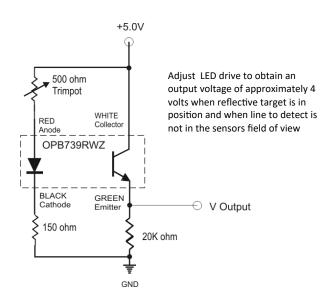
- 1. "d" is the distance from the assembly's lens surface to the reflective surface.
- 2. Measured using 90% diffuse reflectance white test card as the reflecting surface.
- 3. Typical values by design. Rise and Fall times are not tested.
- 4. Methanol or Isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.

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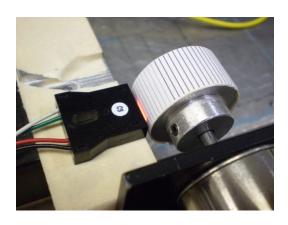
OPB739RWZ



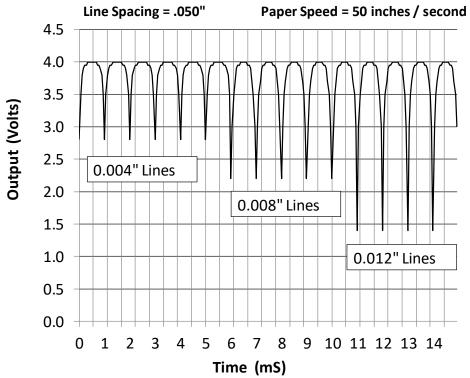
Typical Drive Circuit



Example reflective target with 0.004", 0.008", and .012" line widths spaced 0.050" apart



Typical Output Voltage vs Time



OPB739RWZ



Typical Performance Curves

